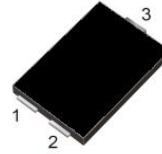


45V Trench MOS Barrier Schottky Rectifier

FEATURES

- Patented Trench MOS Barrier Schottky technology
- Excellent high temperature stability
- Low forward voltage
- Lower power loss/ High efficiency
- High forward surge capability
- Ideal for automated placement
- Moisture sensitivity: level 1, per J-STD-020
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition



TO-277A(SMPC)



MECHANICAL DATA

Case : TO-277A(SMPC)

Molding compound, UL flammability classification rating 94V-0
Base P/N with suffix "G" on packing code - halogen-free, RoHS compliant

Terminal : Matte tin plated leads, solderable per JESD22-B102
Meet JESD 201 class 1A whisker test,
with prefix "H" on packing code meet JESD 201 class 2 whisker test

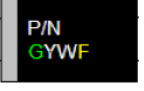
Polarity : Indicated by cathode band

Weight : 0.095 gram (approximately)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T _A =25°C unless otherwise noted)							
PARAMETER		Symbol	B8U45S			Unit	
Maximum Repetitive Peak Reverse Voltage		V _{RRM}	45			V	
Maximum Average Forward Rectified Current		I _{F(AV)}	8			A	
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load per Diode		I _{FSM}	180			A	
Maximum Instantaneous Forward Voltage per Diode (Note 1)	I _F = 8A	V _F	T _A = 25°C	-	0.40	0.50	V
			T _A = 125°C	-	0.34	0.43	
Maximum Instantaneous Reverse Current per Diode at Rated Reverse Voltage		I _R	T _A = 25°C	-	-	15	mA
			T _A = 125°C	-	50	140	
Maximum DC reverse voltage		V _{DC}	32			V	
Typical Thermal Resistance per Diode		R _{θJC}	23			°C/W	
Operating Temperature Range		T _J	- 40 to + 150			°C	
Storage Temperature Range		T _{STG}	- 40 to + 150			°C	

Note1 : Pulse Test with Pulse Width=300µs, 1% Duty Cycle

ORDERING INFORMATION				
PART NO.	PACKING CODE	GREEN COMPOUND CODE	PACKAGE	PACKING
B8U45S	S2	Suffix "G"	SMPC	6000/ 13" Plastic reel

MARKING INFORMATION		
	P/N	= 8U45S
	G	= Green Compound
	YW	= Date Code
	F	= Factory Code

RATINGS AND CHATACTERISTICS CURVES

($T_A=25^{\circ}\text{C}$ unless otherwise noted)

FIG.1 FORWARD CURRENT DERATING CURVE

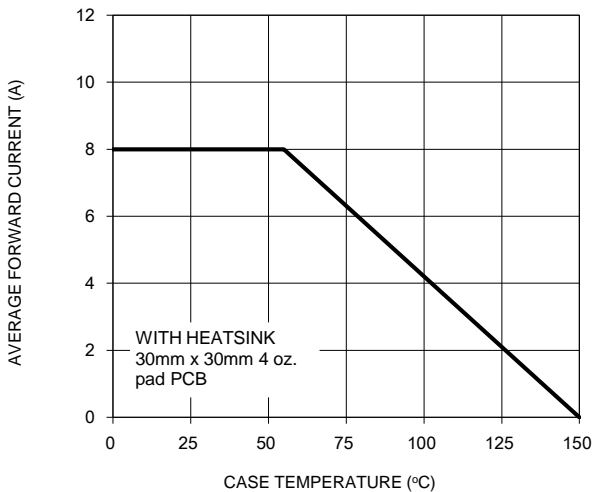


FIG. 2 TYPICAL FORWARD CHARACTERISTICS

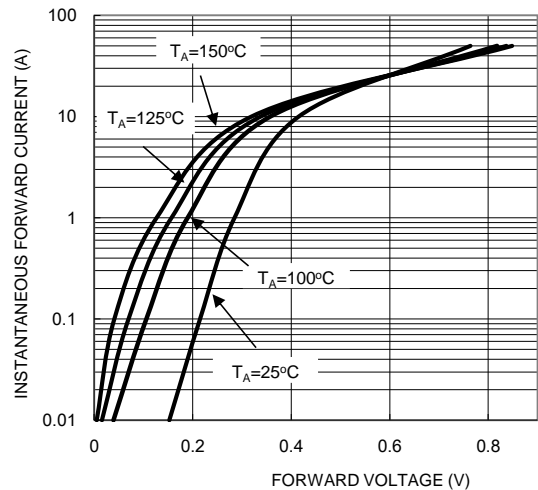


FIG. 3 TYPICAL REVERSE CHARACTERISTICS

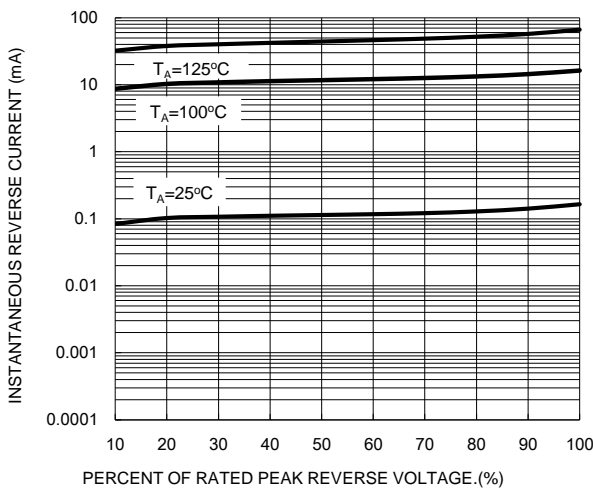
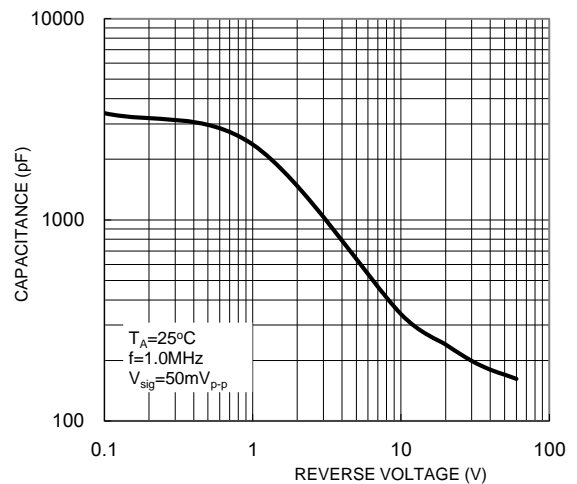
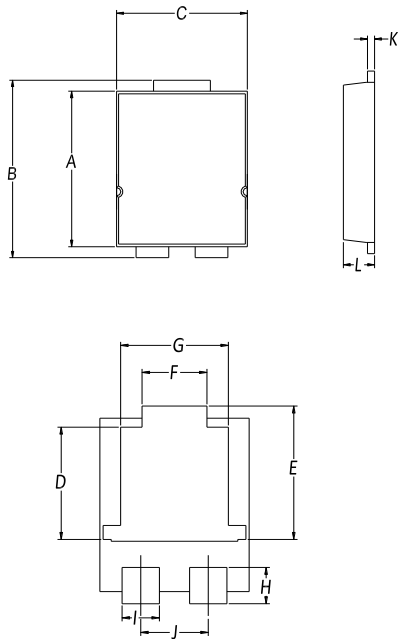
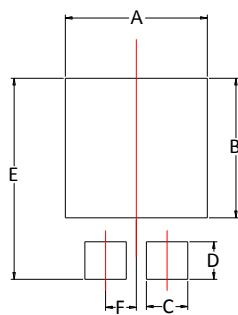


FIG. 4 TYPICAL JUNCTION CAPACITANCE



PACKAGE OUTLINE DIMENSIONS


DIM.	Unit(mm)		Unit(inch)	
	Min	Max	Min	Max
A	5.650	5.750	0.222	0.226
B	6.350	6.650	0.250	0.262
C	4.550	4.650	0.179	0.183
D	3.540	3.840	0.139	0.151
E	4.235	4.535	0.167	0.179
F	1.850	2.150	0.073	0.085
G	3.170	3.470	0.125	0.137
H	1.043	1.343	0.041	0.053
I	1.000	1.300	0.039	0.051
J	1.930	2.230	0.076	0.088
K	0.175	0.325	0.007	0.013
L	1.000	1.200	0.039	0.047

SUGGESTED PAD LAYOUT


Symbol	Unit(mm)
A	4.8
B	4.72
C	1.4
D	1.27
E	6.8
F	1.04